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Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







## **BUV22**

## **SWITCHMODE™** Series **NPN Silicon Power Transistor**

This device is designed for high speed, high current, high power applications.

#### **Features**

- High DC Current Gain:
  - $h_{FE} \min = 20 \text{ at } I_C = 10 \text{ A}$
- Low V<sub>CE(sat)</sub>, V<sub>CE(sat)</sub>
  - $max = 1.0 \text{ V} \text{ at } I_C = 10 \text{ A}$
- Very Fast Switching Times:
  - TF max =  $0.35 \, \mu s$  at  $I_C = 20 \, A$
- Pb-Free Package is Available\*

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V <sub>CEO(SUS)</sub>	250	Vdc
Collector-Base Voltage	V <sub>CBO</sub>	300	Vdc
Emitter-Base Voltage	V <sub>EBO</sub>	7	Vdc
Collector–Emitter Voltage (V <sub>BE</sub> = -1.5 V)	V <sub>CEX</sub>	300	Vdc
Collector–Emitter Voltage (R <sub>BE</sub> = 100 Ω)	V <sub>CER</sub>	290	Vdc
Collector-Current - Continuous - Peak (PW ≤ 10 ms)	I <sub>C</sub>	40 50	Adc Apk
Base-Current Continuous	I <sub>B</sub>	8	Adc
Total Device Dissipation @ T <sub>C</sub> = 25°C	P <sub>D</sub>	250	W
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-65 to 200	°C

#### THERMAL CHARACTERISTICS

Characteristics	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$\theta_{JC}$	0.7	°C/W

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.



#### ON Semiconductor®

http://onsemi.com

## **40 AMPERES NPN SILICON POWER METAL TRANSISTOR** 250 VOLTS - 250 WATTS



TO-204AE (TO-3) **CASE 197A** 

#### **MARKING DIAGRAM**



BUV22 = Device Code G = Pb-Free Package = Assembly Location

= Year WW = Work Week = Country of Origin

#### ORDERING INFORMATION

Device	Package	Shipping
BUV22	TO-204	100 Units / Tray
BUV22G	TO-204 (Pb-Free)	100 Units / Tray

<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

### **BUV22**

## $\textbf{ELECTRICAL CHARACTERISTICS} \ (T_C = 25^{\circ}\text{C unless otherwise noted})$

	Symbol	Min	Max	Unit	
OFF CHARACTERISTICS (Note	e 1)				
Collector–Emitter Sustaining Vo	V <sub>CEO(sus)</sub>	250		Vdc	
Collector Cutoff Current at Rev $(V_{CE} = 300 \text{ V}, V_{BE} = -1.5 \text{ V})$ $(V_{CE} = 300 \text{ V}, V_{BE} = -1.5 \text{ V})$	I <sub>CEX</sub>		3.0 12.0	mAdc	
Collector–Emitter Cutoff Currer (V <sub>CE</sub> = 200 V)	I <sub>CEO</sub>		3.0	mAdc	
Emitter–Base Reverse Voltage (I <sub>E</sub> = 50 mA)	V <sub>EBO</sub>	7		V	
Emitter–Cutoff Current (V <sub>EB</sub> = 5 V)	I <sub>EBO</sub>		1.0	mAdc	
SECOND BREAKDOWN				•	•
Second Breakdown Collector C $(V_{CE} = 20 \text{ V}, t = 1 \text{ s})$ $(V_{CE} = 140 \text{ V}, t = 1 \text{ s})$	I <sub>S/b</sub>	12 0.15		Adc	
ON CHARACTERISTICS (Note	1)			•	•
DC Current Gain (I <sub>C</sub> = 10 A, V <sub>CE</sub> = 4 V) (I <sub>C</sub> = 20 A, V <sub>CE</sub> = 4 V)	h <sub>FE</sub>	20 10	60		
Collector–Emitter Saturation Vo ( $I_C = 10 \text{ A}, I_B = 1 \text{ A}$ ) ( $I_C = 20 \text{ A}, I_B = 2.5 \text{ A}$ )	V <sub>CE(sat)</sub>		1.0 1.5	Vdc	
Base–Emitter Saturation Voltage (I <sub>C</sub> = 40 A, I <sub>B</sub> = 4 A)	V <sub>BE(sat)</sub>		1.5	Vdc	
DYNAMIC CHARACTERISTICS	6	1		1	-
Current Gain — Bandwidth Pro (V <sub>CE</sub> = 15 V, I <sub>C</sub> = 2 A, f = 4 M	f <sub>T</sub>	8.0		MHz	
SWITCHING CHARACTERISTI	CS (Resistive Load)				•
Turn-on Time		t <sub>on</sub>		0.8	μS
Storage Time	$(I_C = 20 \text{ A}, I_{B1} = I_{B2} = 2.5 \text{ A}, V_{CC} = 100 \text{ V}, R_C = 5 \Omega)$	ts		2.0	1
Fall Time	100 = 100 1, 1.0 = 0 15)	t <sub>f</sub>		0.35	
					_

<sup>1.</sup> Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  2%.

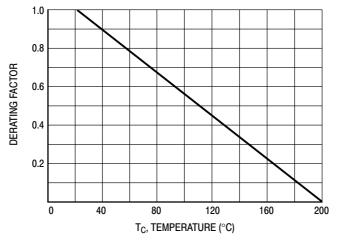


Figure 1. Power Derating

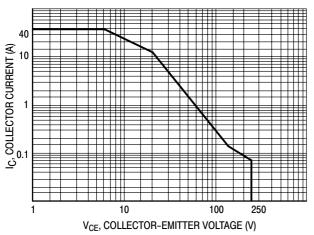
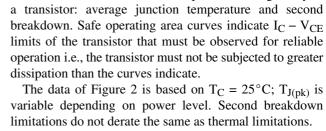


Figure 2. Active Region Safe Operating Area



variable depending on power level. Second breakdown limitations do not derate the same as thermal limitations.

There are two limitations on the power handling ability of

At high case temperatures, thermal limitations will reduce the power that can handled to values less than the limitations imposed by second breakdown.

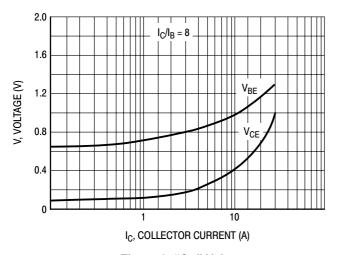


Figure 3. "On" Voltages

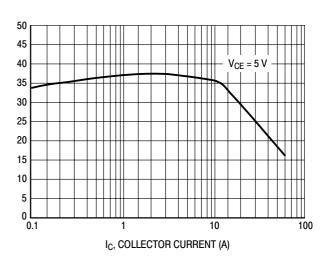


Figure 4. DC Current Gain

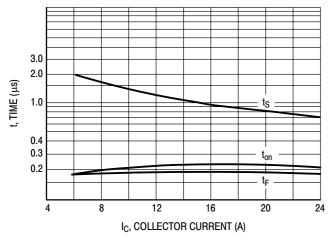


Figure 5. Resistive Switching Performance

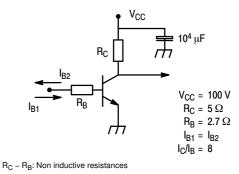
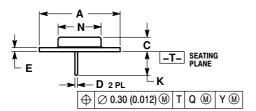


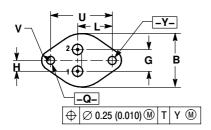
Figure 6. Switching Times Test Circuit

#### BUV22

#### PACKAGE DIMENSIONS

TO-204 (TO-3) CASE 197A-05 ISSUE K





#### NOTES

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.

	INC	HES	MILLIM	IETERS
DIM	MIN	MAX	MIN	MAX
Α	1.530 REF		F 38.86 REF	
В	0.990	1.050	25.15	26.67
С	0.250	0.335	6.35	8.51
D	0.057	0.063	1.45	1.60
Е	0.060	0.070	1.53	1.77
G	0.430 BSC		10.92 BSC	
Н	0.215 BSC		5.46 BSC	
K	0.440	0.480	11.18	12.19
L	0.665 BSC		16.89 BSC	
N	0.760	0.830	19.31	21.08
Q	0.151	0.165	3.84	4.19
U	1.187 BSC		30.15 BSC	
٧	0.131	0.188	3.33	4.77

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